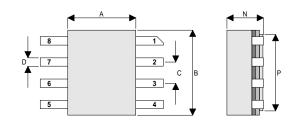
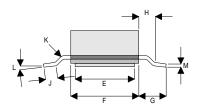


D1211UK

ROHS COMPLIANT METAL GATE RF SILICON FET

MECHANICAL DATA





SO8 PACKAGE

PIN 1 - SOURCE PIN 5 - SOURCE PIN 2 - DRAIN PIN 6 - GATE PIN 3 - DRAIN PIN 7 - GATE PIN 4 - SOURCE PIN 8 - SOURCE

Dim.	mm	Tol.	Inches	Tol.	
Α	4.06	±0.08	0.160	±0.003	
В	5.08	±0.08	0.200	±0.003	
С	1.27	±0.08	0.050	±0.003	
D	0.51	±0.08	0.020	±0.003	
Е	3.56	±0.08	0.140	±0.003	
F	4.06	±0.08	0.160	±0.003	
G	1.65	±0.08	0.065	±0.003	
Н	0.76	+0.25	0.030	+0.010	
"		-0.00		-0.000	
J	0.51	Min.	0.020	Min.	
	1.02	Max.	0.040	Max.	
K	45°	Max.	45°	Max.	
L	0°	Min.	0°	Min.	
-	7° Max.		7°	Max.	
M	0.20	±0.08	0.008	±0.003	
N	2.18	Max.	0.086	Max.	
Р	4.57	±0.08	0.180	±0.003	

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET 10W - 12.5V - 500MHzSINGLE ENDED

FEATURES

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- VERY LOW C_{rss}
- SIMPLE BIAS CIRCUITS
- LOW NOISE
- HIGH GAIN 10 dB MINIMUM

APPLICATIONS

 HF/VHF/UHF COMMUNICATIONS from 1 MHz to 1 GHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

P_{D}	Power Dissipation	30W
BV _{DSS}	Drain – Source Breakdown Voltage	40V
BV_{GSS}	Gate – Source Breakdown Voltage	±20V
I _{D(sat)}	Drain Current	10A
T _{stg}	Storage Temperature	−65 to 150°C
Tj	Maximum Operating Junction Temperature	200°C

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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Website: http://www.semelab.co.uk



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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
D\/	Drain-Source	V _{GS} = 0	I _D = 10mA	40			V
BV _{DSS}	Breakdown Voltage	VGS = 0	ID = IOIIIA	40			V
I _{DSS}	Zero Gate Voltage	\/ _ 12.5\/	V V - 0			1	mA
	Drain Current	$V_{DS} = 12.5V$	$V_{GS} = 0$			Į	IIIA
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	$V_{DS} = 0$			1	μΑ
V _{GS(th)}	Gate Threshold Voltage*	I _D = 10mA	$V_{DS} = V_{GS}$	1		7	V
9 _{fs}	Forward Transconductance*	V _{DS} = 10V	I _D = 1A	0.8			S
G _{PS}	Common Source Power Gain	P _O = 10W		10			dB
η	Drain Efficiency	V _{DS} = 12.5V	$I_{DQ} = 0.4A$	50			%
VSWR	Load Mismatch Tolerance	f = 500MHz		20:1			_
C _{iss}	Input Capacitance	$V_{DS} = 0V \qquad V_{G}$	$_{iS} = -5V f = 1MHz$			60	pF
C _{oss}	Output Capacitance	$V_{DS} = 12.5V V_{G}$	$_{iS} = 0$ $f = 1MHz$			40	pF
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = 12.5V V_{G}$	$_{S} = 0$ $f = 1MHz$			4	pF

^{*} Pulse Test: Pulse Duration = 300 μs , Duty Cycle $\leq 2\%$

THERMAL DATA

R _{THj-0}	case	Thermal Resistance Junction – Case	Max. 6°C / W
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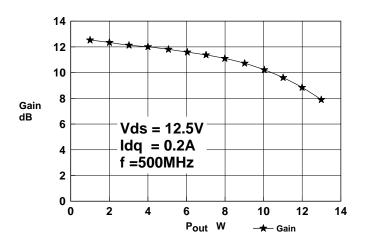
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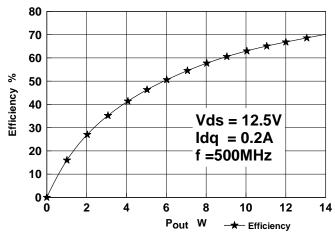


Figure 1 – Gain vs. Power Output.

Figure 2 – Efficiency vs. Power Output.

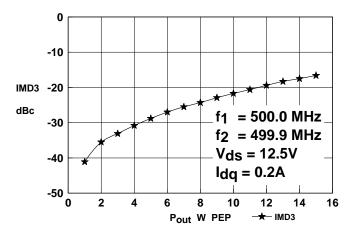


Figure 3 - IMD vs. Output Power.

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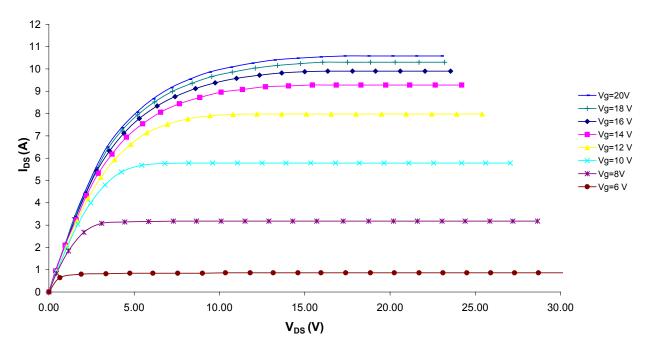


Figure 4 - Typical IV Characteristics.

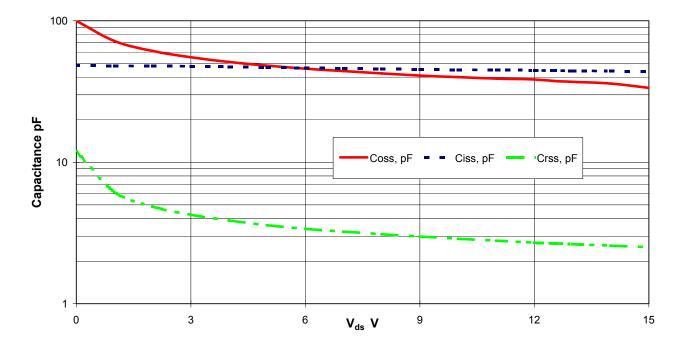


Figure 5 - Typical CV Characteristics.

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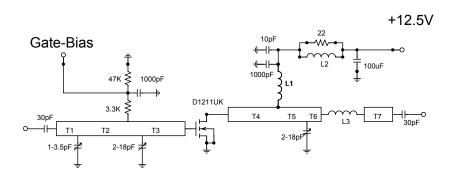
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Document Number 3172







D1211UK 500MHz TEST FIXTURE

Substrate 0.8mm PTFE/glass, Er=2.5

All microstrip lines W=1.5mm

T16mm

T2 35mm

T3 16mm

T4 11mm

T5 7mm

T6 7mm

T7 23mm

L1 6 turns 0.5mm dia enamelled copper wire, 4mm i.d.

L2 1.5 turns 0.5mm enamelled copper wire on 2 hole ferrite core

L3 1/16" dia wire hairpin loop 15mm long

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